# **Results of the EXAFS experiment 'Determination of Er sites in Er-implanted silica containing Si** nanocrystals by means of EXAFS spectroscopy'.

### Samples:

SiO <sub>x</sub> (x<2)	+ (RT, (19A,	annealing 800°C, 21A,	1250°C) 23A)	+ Er implant $(5x10^{14} \text{ Er}^+/\text{cm}^2)$ +annealing (900°C, 1h)
SiO <sub>2</sub> with Si	nc +	Er im $5.4x10^{19}$ En $2.1x10^{20}$ En $1.4x10^{21}$ En	nplant r/cm <sup>3</sup> (1371 r/cm <sup>3</sup> (1192 r/cm <sup>3</sup> (1212	+ annealing (900°C, 1h) B) A) A)

The EXAFS experiment was performed at the Italian beamline GILDA of the European Synchrotron Radiation Facility at the Er  $L_{III}$ -edge in fluorescence mode, cooling the samples at T=77K. The x-ray beam from a bending magnet was dynamically focused on the sample. The Er-L $\alpha$  fluorescence signal from the samples was recorded by a 13-element high-purity Ge detector.

#### First shell analysis.

All the recorded EXAFS spectra exhibit one main oscillation (see Fig. 1), related to the Er-O coordination. Correspondingly, in the Fourier transform moduli of the spectra (see Fig. 2) the peak of the first coordination shell (Er-O) is clearly visible at about  $R\sim1.5-2$ Å.

The first shell analysis was performed exploiting the FEFF8-FEFFIT software package, fitting the first shell back-transformed signal (q-space), using the phase and amplitude calculated for the Er-O coordination of the  $Er_2Si_2O_7$  model compound. In the Fig. 1, the comparison between the best-fitting curve and the experimental spectra is reported; the fitting results are collected in Table 1.

	Er-O				
sample	No	R	$\sigma^2$		
		(Å)	$(\times 10^{-4} \text{\AA}^2)$		
19A	2.2±0.4	2.05±0.01	60±27		
21A	4.4±0.6	$2.09 \pm 0.02$	250±30		
23A	3.5±0.5	$2.10\pm0.02$	189±30		
137B	3.1±0.3	$2.095 \pm 0.008$	115±15		
119A	5.8±0.2	2.161±0.003	240±7		
121A	6.3±1.3	2.23±0.02	220±46		
$Er_2O_3$					
site I	6	2.27			
site II	4	2.24			
	2	2.31			

# It is found that:

- The Er-O coordination distance is always shorter than the corresponding average value for the crystalline  $Er_2O_3$ ; the largest value is R=2.23Å, corresponding to the sample 121A.

- The coordination number is lower than that of the crystalline  $Er_2O_3$ , but for the 119A and 121A samples.

- There is a general correlation between the coordination number and the coordination distance, larger is the first, larger is the second (see Fig. 3).

- The effect of heating the substrate before the Er implantation is to increase the coordination number of O atoms around Er.

- The effect of increasing the Er implantation dose is to increase the coordination number of O atoms around Er.

- In Fig. 3 the results obtained (the red line is a guideline for the eye) are compared with those in literature for Er-implanted silica (Marcus et al, JNCS 91 and JNCS 96). Marcus et al. (JNCS96) found that in Er-implanted silica (flat-top profile, E~5MeV, top concentration = 1at%), the effect of annealing in vacuo (T=900C, 1h) is to increase the coordination number and the Er-O average distance from N=2.2, R=2.11 Å (marker c, Fig. 3) towards N=6.3, R=2.24 Å (marker d, Fig. 3). The same annealing did not turn out in significant structural modification if the Er concentration is lower (0.1at%, markers a and b).

## Second shell analysis.

In most all the spectra a second shell is visible, located at about R=3 Å. The analysis of the signal from the first two shells was based on the GNXAS code, considering a model for the Er site in which each first-shell O atom is bonded with a Si atom in a typical SiO<sub>2</sub> tetrahedron. In the fitting, both the single scattering signals (Er-O and Er-Si) and the three-atoms scattering signal (from the Er-O-Si triangle) was considered. This model reproduces the experimental data of the samples 19A, 137B and 121A, as shown in Fig. 4.

Possible Er-Er coordination, if present, is below the detectable limit.



Fig. 1







Fig. 3